RENESAS

Lower Power 3.3V CMOS Fast SRAM 256K (32K x 8-Bit)

71V256SA

Features

- **Ideal for high-performance processor secondary cache**
- **Commercial (0°C to +70°C) and Industrial (–40°C to +85°C) temperature range options**
- **Fast access times:**
  - *Commercial and Industrial: 12/15/20ns*
- **Low standby current (maximum):**
  - *2mA full standby*
- **Small packages for space-efficient layouts:**
  - *28-pin 300 mil SOJ*
  - *28-pin TSOP Type I*
- **Produced with advanced high-performance CMOS technology**
- **Inputs and outputs are LVTTL-compatible**
- **Single 3.3V(±0.3V) power supply**
- **Industrial temperature range (–40°C to +85°C) is available for selected speeds**
- **Green parts available, see ordering information**

Description

The IDT71V256SA is a 262,144-bit high-speed static RAM organized as 32K x 8. It is fabricated using a high-performance, high-reliability CMOS technology.

The IDT71V256SA has outstanding low power characteristics while at the same time maintaining very high performance. Address access times of as fast as 12ns are ideal for 3.3V secondary cache in 3.3V desktop designs.

When power management logic puts the IDT71V256SA in standby mode, its very low power characteristics contribute to extended battery life. By taking $\overline{CS}$ HIGH, the SRAM will automatically go to a low power standby mode and will remain in standby as long as $\overline{CS}$ remains HIGH. Furthermore, under full standby mode ($\overline{CS}$ at CMOS level, f=0), power consumption is guaranteed to always be less than 6.6mW and typically will be much smaller.

The IDT71V256SA is packaged in a 28-pin 300 mil SOJ and a 28-pin 300 mil TSOP Type I.

Functional Block Diagram

3101 drw 01

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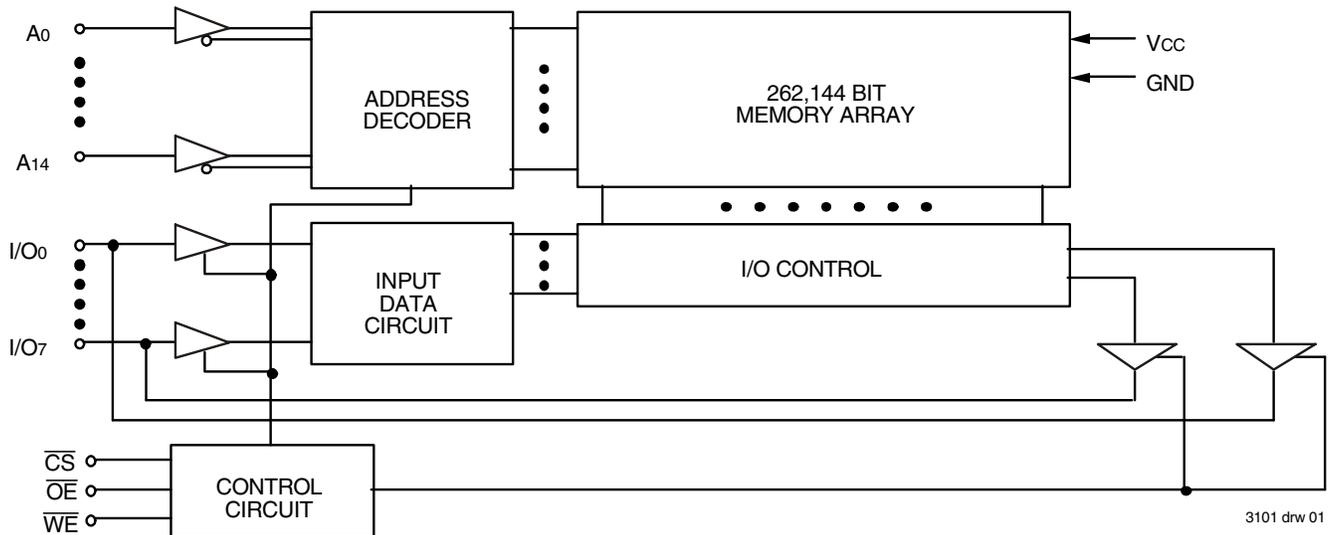
Pin Configurations[1]

DIP/SOJ
Top View

3101 drw 02

TSOP
Top View

3101 drw 03
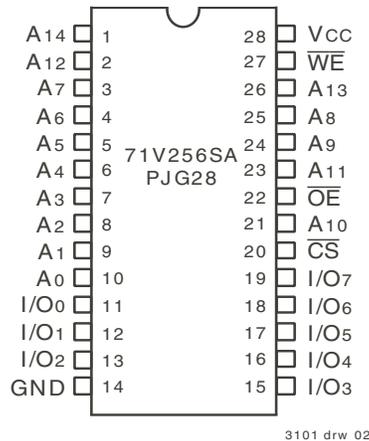
NOTE:
1. This text does not indicate orientation of actual part-marking.

Pin Descriptions

Name	Description
A_0 - A_{14}	Addresses
I/O_0 - I/O_7	Data Input/Output
$\overline{CS}$	Chip Select
$\overline{WE}$	Write Enable
$\overline{OE}$	Output Enable
GND	Ground
V_{CC}	Power

3101 tbl 01

Truth Table[1]

$\overline{WE}$	$\overline{CS}$	$\overline{OE}$	I/O	Function
X	H	X	High-Z	Standby (I_{SB})
X	V_{HC}	X	High-Z	Standby (I_{SB1})
H	L	H	High-Z	Output Disable
H	L	L	D_{OUT}	Read
L	L	X	D_{IN}	Write

3101 tbl 02

NOTE:
1. H = V_{IH}, L = V_{IL}, X = Don't Care

Absolute Maximum Ratings[1]

Symbol	Rating	Com'l	Unit
V_{CC}	Supply Voltage Relative to GND	-0.5 to +4.6	V
V_{TERM}[2]	Terminal Voltage Relative to GND	-0.5 to V_{CC}+0.5	V
T_{BIAS}	Temperature Under Bias	-55 to +125	°C
T_{STG}	Storage Temperature	-55 to +125	°C
P_T	Power Dissipation	1.0	W
I_{OUT}	DC Output Current	50	mA

3101 tbl 03

NOTES:
1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. Input, Output, and I/O terminals; 4.6V maximum.

Capacitance
(T_A = +25°C, f = 1.0MHz, SOJ package)

Symbol	Parameter[1]	Conditions	Max.	Unit
C_{IN}	Input Capacitance	V_{IN} = 3dV	6	pF
C_{OUT}	Output Capacitance	V_{OUT} = 3dV	7	pF

3101 tbl 04

NOTE:
1. This parameter is determined by device characterization, but is not production tested.

Recommended Operating Temperature and Supply Voltage

Grade	Temperature	GND	Vcc
Commercial	0°C to +70°C	0V	3.3V ± 0.3V
Industrial	-40°C to +85°C	0V	3.3V ± 0.3V

3101 tbl 05

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Recommended DC Operating Conditions

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{CC}	Supply Voltage	3.0	3.3	3.6	V
GND	Ground	0	0	0	V
V_{IH}	Input High Voltage - Inputs	2.0	—	V_{CC} +0.3	V
V_{IH}	Input High Voltage - I/O	2.0	—	V_{CC} +0.3	V
V_{IL}	Input Low Voltage	-0.3[1]	—	0.8	V

3101 tbl 06

NOTE:
1. V_{IL} (min.) = –2.0V for pulse width less than 5ns, once per cycle.

DC Electrical Characteristics[1]

(VCC = 3.3V ± 0.3V, VLC = 0.2V, VHC = VCC - 0.2V, Commercial and Industrial Temperature Ranges)

Symbol	Parameter	71V256SA12	71V256SA15	71V256SA20	Unit
I_{CC}	Dynamic Operating Current $\overline{CS} \leq V_{IL}$, Outputs Open, V_{CC} = Max., f = f_{MAX}[2]	90	85	85	mA
I_{SB}	Standby Power Supply Current (TTL Level) $\overline{CS} = V_{IH}$, V_{CC} = Max., Outputs Open, f = f_{MAX}[2]	20	20	20	mA
I_{SB1}	Full Standby Power Supply Current (CMOS Level) $\overline{CS} \geq V_{HC}$, V_{CC} = Max., Outputs Open, f = 0[2], $V_{IN} \leq V_{LC}$ or $V_{IN} \geq V_{HC}$	2	2	2	mA

3101 tbl 07

NOTES:
1. All values are maximum guaranteed values.
2. f_{MAX} = 1/t_{RC}, only address inputs cycling at f_{MAX}; f = 0 means that no inputs are cycling.

DC Electrical Characteristics

(V_{CC} = 3.3V± 0.3V)

Symbol	Parameter	Test Conditions	IDT71V256SA			Unit
			Min.	Typ.	Max.	
$|I_{LI}|$	Input Leakage Current	V_{CC} = Max., V_{IN} = GND to V_{CC}	—	—	2	µA
$|I_{LO}|$	Output Leakage Current	V_{CC} = Max., $\overline{CS} = V_{IH}$, V_{OUT} = GND to V_{CC}	—	—	2	µA
V_{OL}	Output Low Voltage	I_{OL} = 8mA, V_{CC} = Min.	—	—	0.4	V
V_{OH}	Output High Voltage	I_{OH} = -4mA, V_{CC} = Min.	2.4	—	—	V

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AC Test Conditions

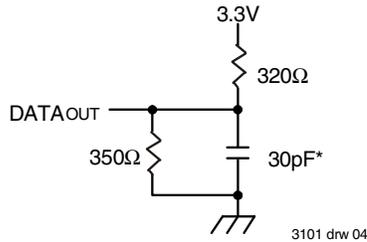|	
Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	3ns
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
AC Test Load	See Figures 1 and 2

3101 tbl 09
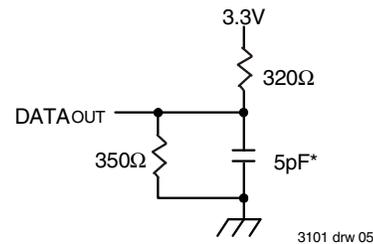

Figure 1. AC Test Load

Figure 2. AC Test Load
(for t_{CLZ}, t_{OLZ}, t_{CHZ}, t_{OHZ}, t_{OW}, t_{WHZ})

Includes scope and jig capacitances

AC Electrical Characteristics

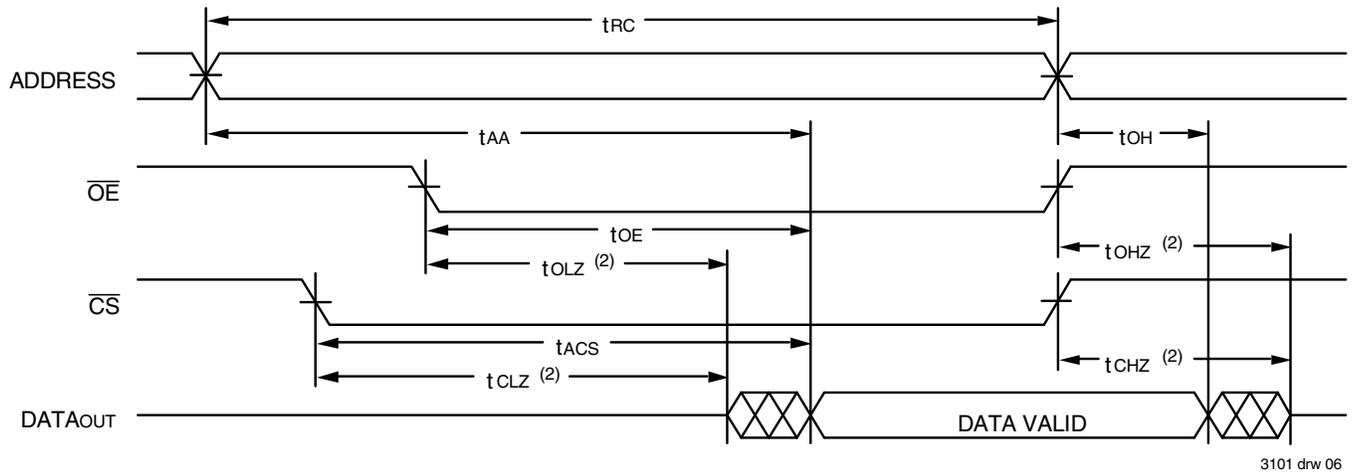(V_{CC} = 3.3V ± 0.3V, Commercial and Industrial Temperature Ranges)

Symbol	Parameter	71V256SA12		71V256SA15		71V256SA20		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
Read Cycle								
t_{RC}	Read Cycle Time	12	—	15	—	20	—	ns
t_{AA}	Address Access Time	—	12	—	15	—	20	ns
t_{ACS}	Chip Select Access Time	—	12	—	15	—	20	ns
t_{CLZ}[1]	Chip Select to Output in Low-Z	5	—	5	—	5	—	ns
t_{CHZ}[1]	Chip Select to Output in High-Z	0	8	0	9	0	10	ns
t_{OE}	Output Enable to Output Valid	—	6	—	7	—	8	ns
t_{OLZ}[1]	Output Enable to Output in Low-Z	3	—	0	—	0	—	ns
t_{OHZ}[1]	Output Disable to Output in High-Z	2	6	0	7	0	8	ns
t_{OH}	Output Hold from Address Change	3	—	3	—	3	—	ns
Write Cycle								
t_{WC}	Write Cycle Time	12	—	15	—	20	—	ns
t_{AW}	Address Valid to End-of-Write	9	—	10	—	15	—	ns
t_{CW}	Chip Select to End-of-Write	9	—	10	—	15	—	ns
t_{AS}	Address Set-up Time	0	—	0	—	0	—	ns
t_{WP}	Write Pulse Width	9	—	10	—	15	—	ns
t_{WR}	Write Recovery Time	0	—	0	—	0	—	ns
t_{DW}	Data to Write Time Overlap	6	—	7	—	8	—	ns
t_{DH}	Data Hold from Write Time	0	—	0	—	0	—	ns
t_{OW}[1]	Output Active from End-of-Write	4	—	4	—	4	—	ns
t_{WHZ}[1]	Write Enable to Output in High-Z	1	8	1	9	1	10	ns

3101 tbl 10

NOTE:
1. This parameter guaranteed with the AC test load (Figure 2) by device characterization, but is not production tested.
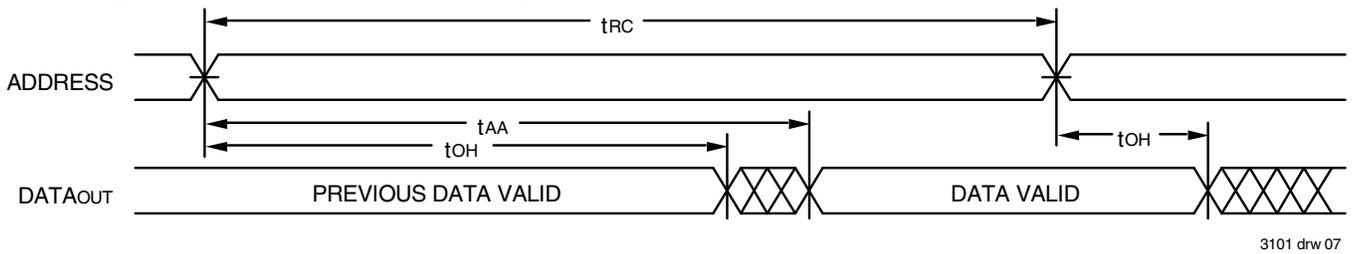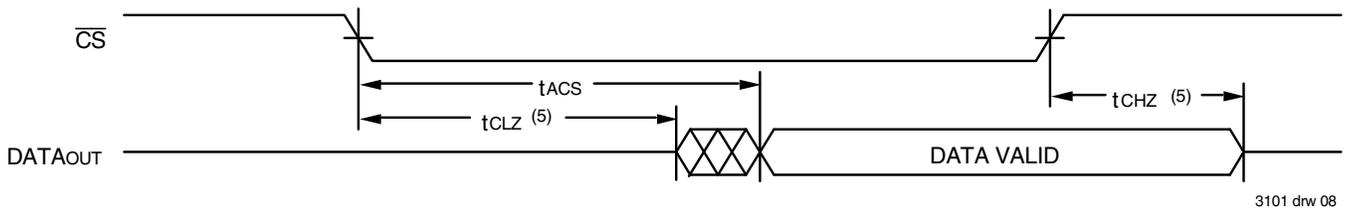
Timing Waveform of Read Cycle No. 1[1]

ADDRESS

t_{RC}

$\overline{OE}$

t_{AA}

t_{OE}

t_{OLZ} [2]

$\overline{CS}$

t_{ACS}

t_{CLZ} [2]

t_{OH}

t_{OHZ} [2]

t_{CHZ} [2]

DATA$_{OUT}$

DATA VALID

3101 drw 06

NOTES:
1. $\overline{WE}$ is HIGH for Read cycle.
2. Transition is measured ±200mV from steady state.

Timing Waveform of Read Cycle No. 2[1,2,4]

ADDRESS

t_{RC}

t_{AA}

t_{OH}

t_{OH}

DATA$_{OUT}$

PREVIOUS DATA VALID

DATA VALID

3101 drw 07

Timing Waveform of Read Cycle No. 3[1,3,4]

$\overline{CS}$

t_{ACS}

t_{CLZ} [5]

t_{CHZ} [5]

DATA$_{OUT}$

DATA VALID

3101 drw 08

NOTES:
1. $\overline{WE}$ is HIGH for Read cycle.
2. Device is continuously selected, $\overline{CS}$ is LOW.
3. Address valid prior to or coincident with $\overline{CS}$ transition LOW.
4. $\overline{OE}$ is LOW.
5. Transition is measured ±200mV from steady state.

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Timing Waveform of Write Cycle No. 1 ($\overline{WE}$ Controlled Timing)[1,2,4,6]
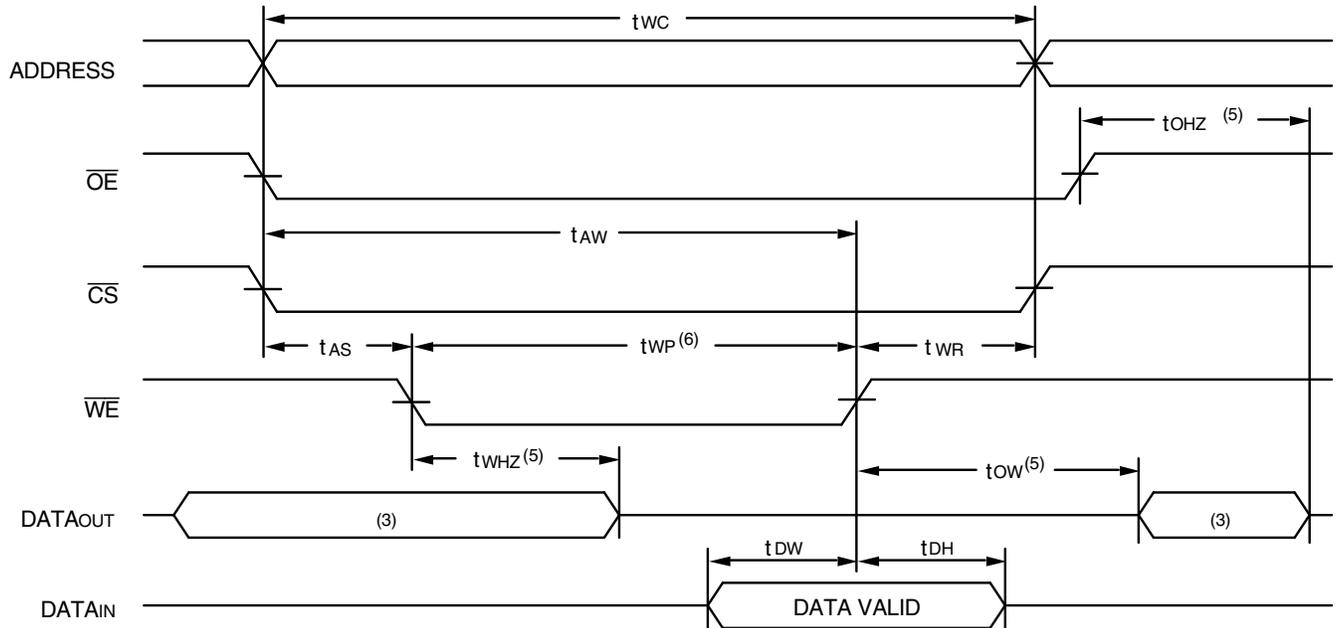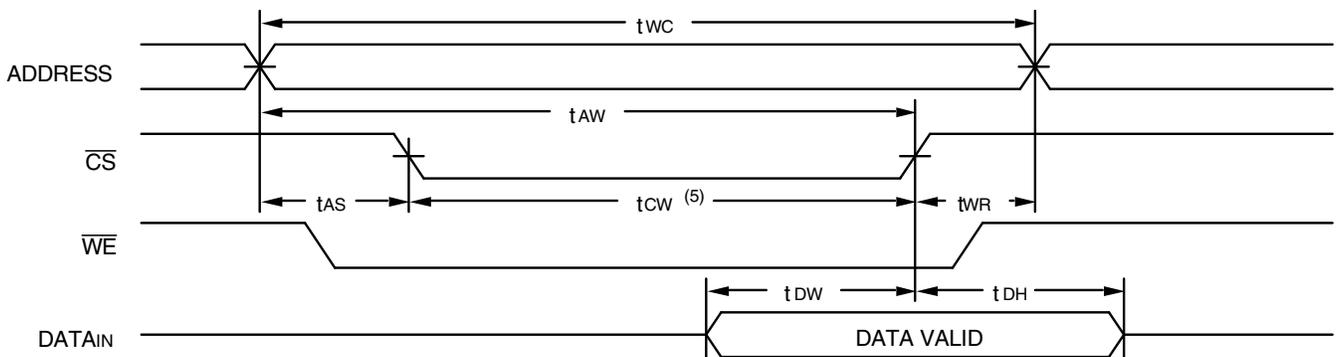

3101 drw 09

NOTES:
1. A write occurs during the overlap of a LOW $\overline{CS}$ and a LOW $\overline{WE}$.
2. t_{WR} is measured from the earlier of $\overline{CS}$ or $\overline{WE}$ going HIGH to the end of the write cycle.
3. During this period, I/O pins are in the output state so that the input signals must not be applied.
4. If the $\overline{CS}$ LOW transition occurs simultaneously with or after the $\overline{WE}$ LOW transition, the outputs remain in a high-impedance state.
5. Transition is measured ±200mV from steady state.
6. If $\overline{OE}$ is LOW during a $\overline{WE}$ controlled write cycle, the write pulse width must be the larger of t_{WP} or (t_{WHZ} + t_{DW}) to allow the I/O drivers to turn off and data to be placed on the bus for the required t_{DW}. If $\overline{OE}$ is HIGH during a $\overline{WE}$ controlled write cycle, this requirement does not apply and the write pulse can be as short as the specified t_{WP}.

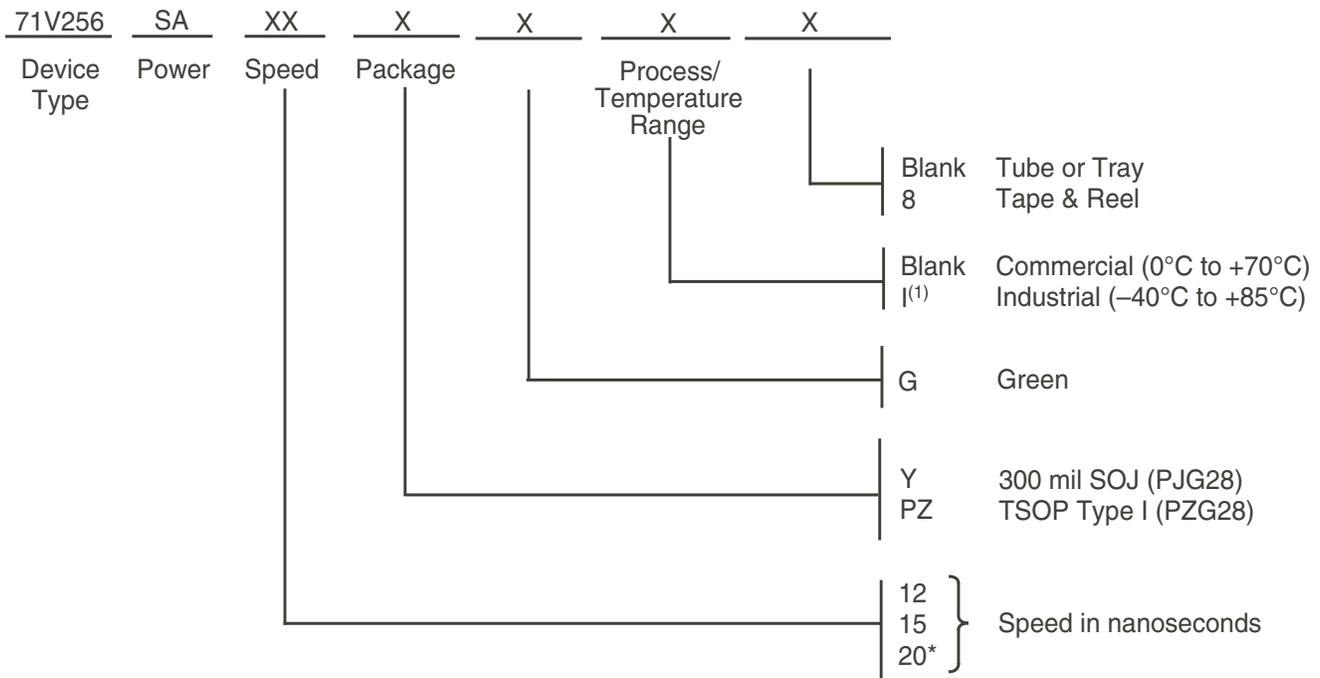## Timing Waveform of Write Cycle No. 2 ($\overline{CS}$ Controlled Timing)[1,2,3,4]

3101 drw 10

NOTES:
1. $\overline{WE}$ or $\overline{CS}$ must be HIGH during all address transitions.
2. A write occurs during the overlap of a LOW $\overline{CS}$ and a LOW $\overline{WE}$.
3. t_{WR} is measured from the earlier of $\overline{CS}$ or $\overline{WE}$ going HIGH to the end of the write cycle.
4. If the $\overline{CS}$ LOW transition occurs simultaneously with or after the $\overline{WE}$ LOW transition, the outputs remain in a high-impedance state.
5. If $\overline{OE}$ is LOW during a $\overline{WE}$ controlled write cycle, the write pulse width must be the larger of t_{WP} or (t_{WHZ} + t_{DW}) to allow the I/O drivers to turn off and data to be placed on the bus for the required t_{DW}. If $\overline{OE}$ is HIGH during a $\overline{WE}$ controlled write cycle, this requirement does not apply and the write pulse can be as short as the specified t_{WP}.

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Ordering Information

```
71V256   SA    XX    X     X     X     X
```

Device Type	Power	Speed	Package		Process/Temperature Range	

Blank	Tube or Tray
8	Tape & Reel

Blank	Commercial (0°C to +70°C)
I(1)	Industrial (−40°C to +85°C)

G	Green

Y	300 mil SOJ (PJG28)
PZ	TSOP Type I (PZG28)

12	
15	Speed in nanoseconds
20*	

* Available in TSOP package only.

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NOTE:
1. Contact your local sales office for industrial temp. range for other speeds, packages and powers.

Orderable Part Information

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
12	71V256SA12PZG	PZG28	TSOP	C
	71V256SA12PZG8	PZG28	TSOP	C
	71V256SA12PZGI	PZG28	TSOP	I
	71V256SA12PZGI8	PZG28	TSOP	I
	71V256SA12YG	PJG28	SOJ	C
	71V256SA12YG8	PJG28	SOJ	C
	71V256SA12YGI	PJG28	SOJ	I
	71V256SA12YGI8	PJG28	SOJ	I
15	71V256SA15PZG	PZG28	TSOP	C
	71V256SA15PZG8	PZG28	TSOP	C
	71V256SA15PZGI	PZG28	TSOP	I
	71V256SA15PZGI8	PZG28	TSOP	I
	71V256SA15YG	PJG28	SOJ	C
	71V256SA15YG8	PJG28	SOJ	C
	71V256SA15YGI	PJG28	SOJ	I
	71V256SA15YGI8	PJG28	SOJ	I
20	71V256SA20PZG	PZG28	TSOP	C
	71V256SA20PZG8	PZG28	TSOP	C
	71V256SA20PZGI	PZG28	TSOP	I
	71V256SA20PZGI8	PZG28	TSOP	I

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Datasheet Document History

1/7/00		Updated to new format
	Pg. 1, 3, 4, 7	Expanded Industrial Temperature offerings
	Pg. 1, 2, 7	Removed 28-pin 300 mil plastic DIP package offering
	Pg. 6	Removed Note No. 1 from Write Cycle No. 1 diagram; renumbered notes and footnotes
	Pg. 7	Revised Ordering Information
	Pg. 8	Added Datasheet Document History
08/09/00		Not recommended for new designs
02/01/01		Removed "Not recommended for new designs"
06/21/02	Pg. 7	Added tape and reel option to the ordering information
01/30/04	Pg. 7	Added "restricted hazardous substance device" to order information.
02/20/09	Pg. 7	Removed "IDT" from ordering parts
06/11/12	Pg. 3	Corrected Recommended DC Operation Conditions Max V_{IH} from 5.0 to Vcc+0.3V
	Pg. 7	Added Green designator to ordering information
	Pg. 7	Corrected footnote in the ordering information from "available in SOJ package only" to "available in TSOP package only"
07/24/14	Pg.7	Added tube or tray to the ordering information
08/18/15	Pg.1 & 7	Removed commercial 10ns speed offering & added green parts available to features
	Pg.2 & 7	Removed "-X" extensions from all pin configurations SOJ28 & TSOP28
	Pg. 3 & 4	Removed commercial 10ns speed offering columns from the DC & AC Elec tables
	Pg.7	Updated the Industrial and Green footnotes in the Ordering Information
06/02/20	Pg.1 - 9	Rebranded as Renesas datasheet
	Pg.2 & 7	Updated package codes
	Pg.7	Added Orderable Part Information

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71V256SA10YG 71V256SA15PZGI8 71V256SA15PZG 71V256SA15YGI 71V256SA12YGI8 71V256SA20PZG8
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